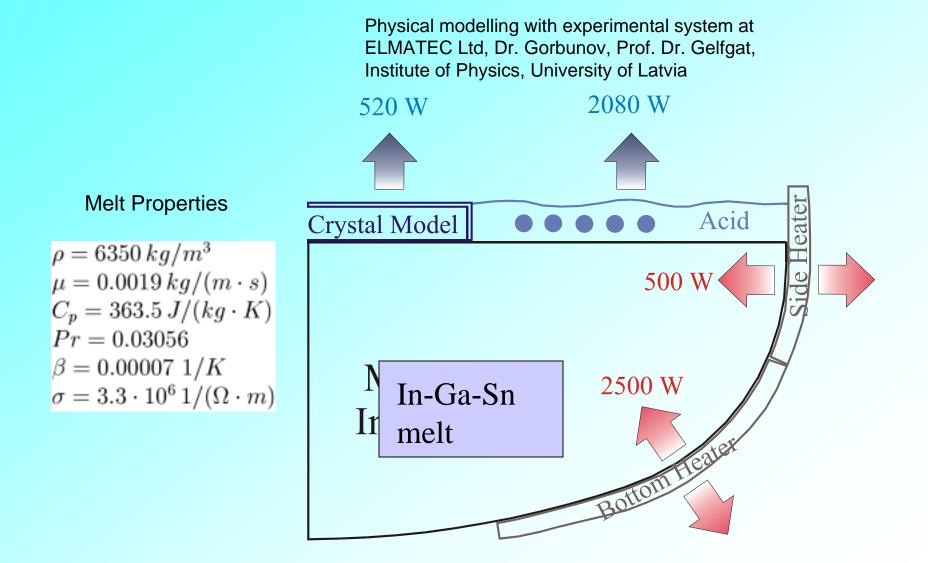
EU COST action P6 "Magnetofluiddynamics" Working Group " Use of magnetic fields in crystal growth"

Workshop in Riga, Latvia, University of Latvia, 13.-14.June 2002 Use of magnetic fields in crystal growth

### Numerical modelling of turbulent flows in industrial CZ silicon large crystal growth with magnetic fields, 2D and 3D analysis

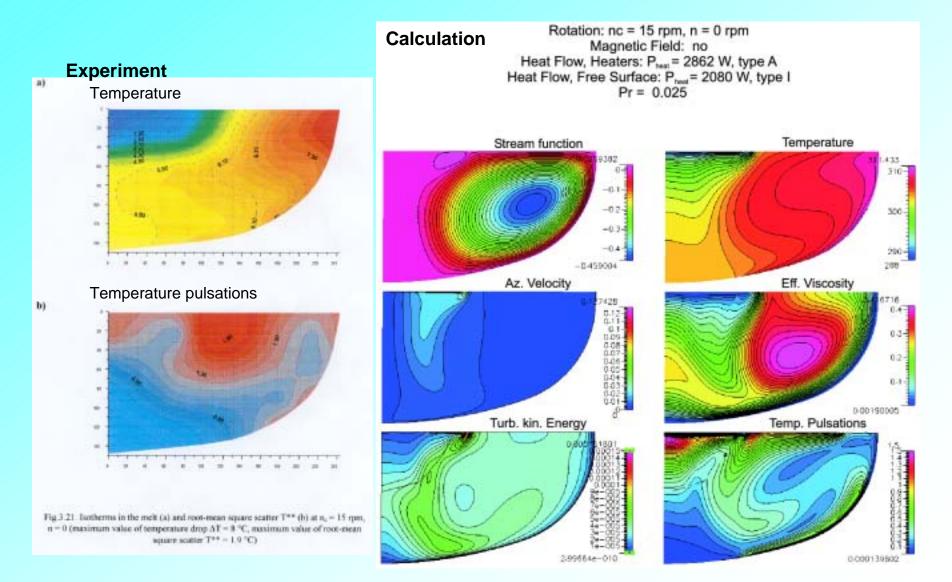
A.Krauze Department of Physics, University of Latvia, Latvia A. Muiznieks Institute for Electrothermal Processes, University of Hanover, Germany +Department of Physics, University of Latvia, Latvia

#### **1. Modelled experimental system with In-Ga-Sn melt**

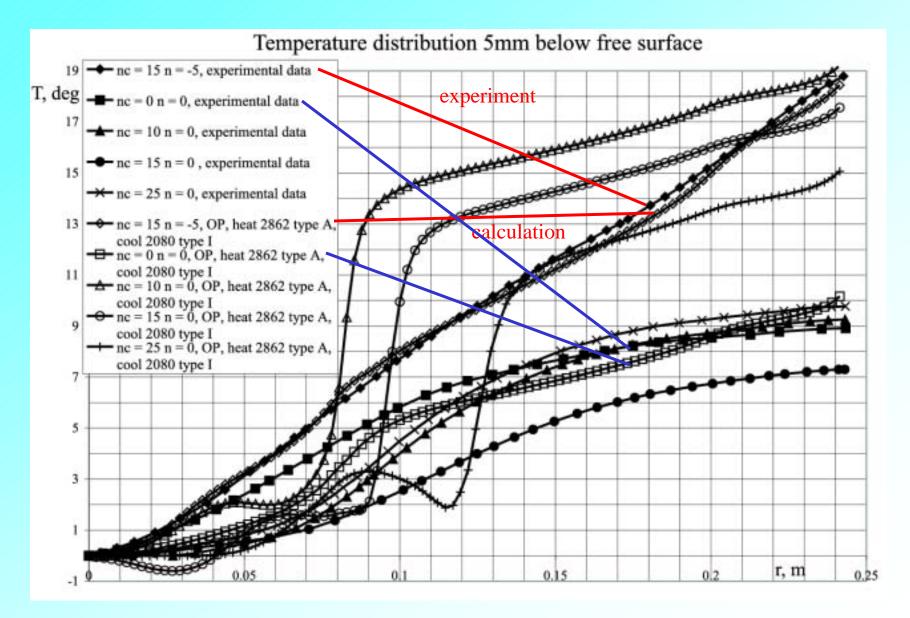


#### **2. Calculation results for the case with motionless crucible**

 $k - \epsilon$  modified low-Re turbulence model (CFD-ACE package)

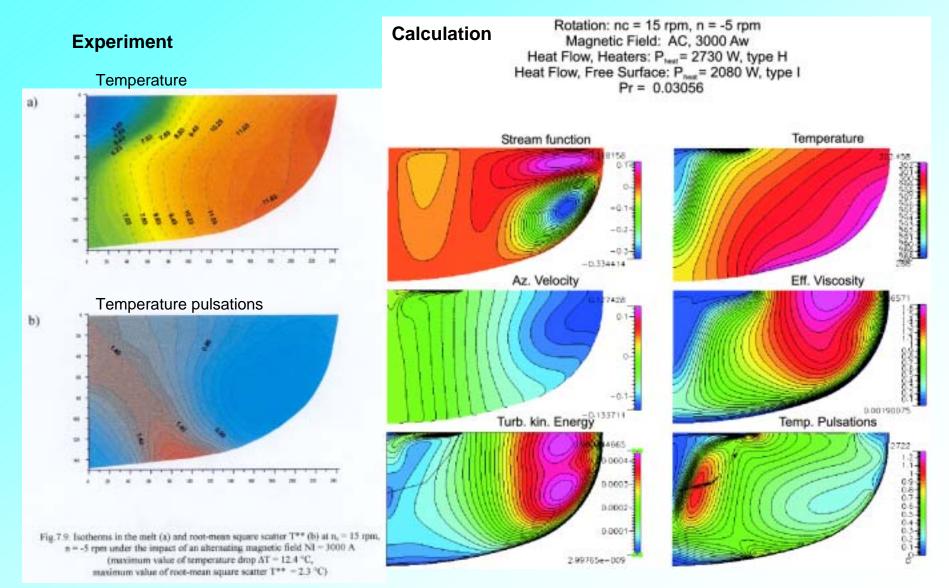


## Calculated and measured radial temperature distribution along free melt surface (5 mm below), cases with motionless crucible



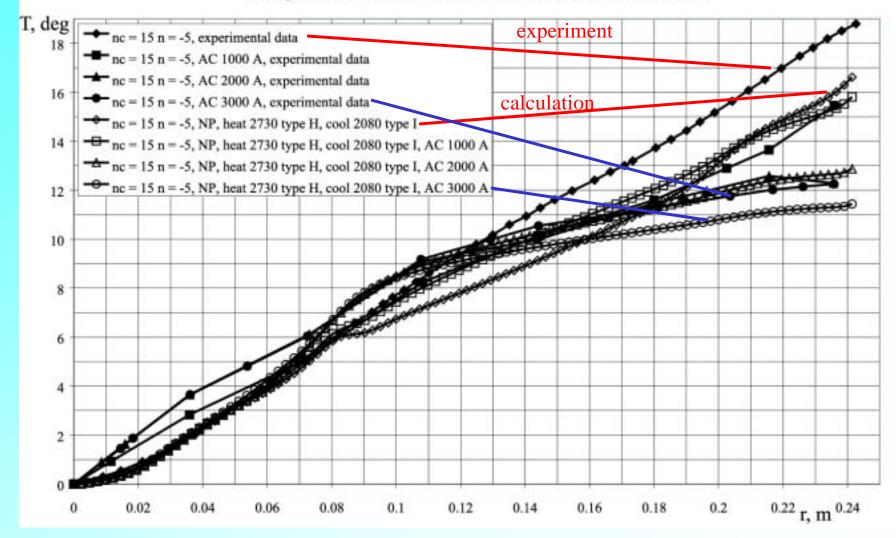
#### 3. Calculation results for the case with alternating magnetic field

 $k - \epsilon$  modified low-Re turbulence model (CFD-ACE package)



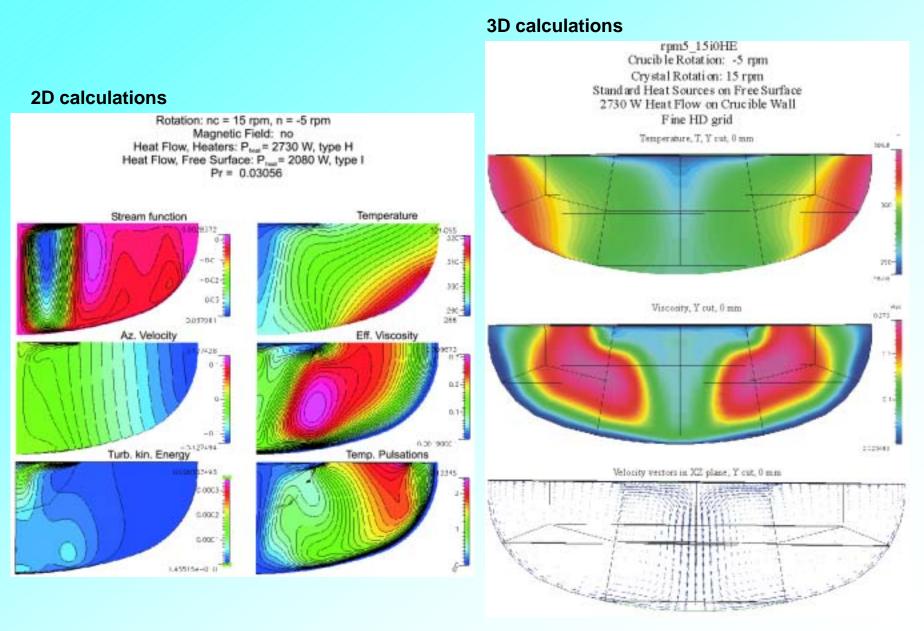
# Calculated and measured radial temperature distribution along free melt surface (5 mm below), cases with alternating magnetic field

#### Temperature distribution 5mm below free surface



#### 4. Comparison of 2D and 3D calculations

 $k - \epsilon$  modified low-Re turbulence model (CFD-ACE package)



### **5.** Conclusions

Summary of the results of comparisons between calculations(2D) and measurements for the temperature distribution in the melt

Absence of MF		Presence of MF	
Proportional Rates	mean	Travelling Field	good
Motionless Crucible	very bad	AC Field	good
Motionless Crystal	very bad	CUSP Field	rather good
TGC case	good	AXIAL Field	bad